

# ON Semiconductor

## Is Now

# onsemi™

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6A, 600V Hyperfast Diodes

The RHRD660S9A-F085 is hyperfast diodes with soft recovery characteristics (trr < 30ns). It has half the recovery time of ultrafast diodes and are silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as freewheeling/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.

Formerly developmental type TA49057.

Features

- Hyperfast with Soft Recovery . . . . . <30ns
- Operating Temperature . . . . . 175°C
- Reverse Voltage Up To . . . . . 600V
- Avalanche Energy Rated
- Planar Construction
- Qualified to AEC Q101
- RoHS Compliant

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose



Ordering Information

PART NUMBER	PACKAGE	BI
RHRD660S9A-F085	TO-252	RHRD660

Symbol



Packaging

JEDEC STYLE TO-252



Absolute Maximum Ratings TC = 25°C, Unless Otherwise Specified

	RHRD660S9A-F085	UNITS
Peak Repetitive Reverse Voltage . . . . .	VRRM 600	V
Working Peak Reverse Voltage . . . . .	VRWM 600	V
DC Blocking Voltage . . . . .	VR 600	V
Average Rectified Forward Current . . . . . (TC = 152°C)	IF(AV) 6	A
Repetitive Peak Surge Current . . . . . (Square Wave, 20kHz)	IFRM 12	A
Nonrepetitive Peak Surge Current . . . . . (Halfwave, 1 Phase, 60Hz)	IFSM 60	A
Maximum Power Dissipation . . . . .	PD 50	W
Avalanche Energy (See Figures 10 and 11) . . . . .	EAVL 10	mJ
Operating and Storage Temperature . . . . .	TSTG, TJ -55 to 175	°C
Maximum Lead Temperature for Soldering (Leads at 0.063 in. (1.6mm) from case for 10s) . . . . .	TL 300	°C
Package Body for 10s, see Tech Brief 334 . . . . .	TPKG 260	°C

**Electrical Specifications**  $T_C = 25^\circ\text{C}$ , Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
$V_F$	$I_F = 6\text{A}$	-	-	2.1	V
	$I_F = 6\text{A}, T_C = 150^\circ\text{C}$	-	-	1.7	V
$I_R$	$V_R = 600\text{V}$	-	-	100	$\mu\text{A}$
	$V_R = 600\text{V}, T_C = 150^\circ\text{C}$	-	-	500	$\mu\text{A}$
$t_{rr}$	$I_F = 1\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	30	ns
	$I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	35	ns
$t_a$	$I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	16	-	ns
$t_b$	$I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	8.5	-	ns
$Q_{RR}$	$I_F = 6\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	45	-	nC
$C_J$	$V_R = 10\text{V}, I_F = 0\text{A}$	-	20	-	pF
$R_{\theta JC}$		-	-	3	$^\circ\text{C}/\text{W}$

**DEFINITIONS**

- $V_F$  = Instantaneous forward voltage ( $pw = 300\mu\text{s}, D = 2\%$ ).
- $I_R$  = Instantaneous reverse current.
- $t_{rr}$  = Reverse recovery time (See Figure 9), summation of  $t_a$  and  $t_b$ .
- $t_a$  = Time to reach peak reverse current (See Figure 9).
- $t_b$  = Time from peak  $I_{RM}$  to projected zero crossing, based on a straight line from peak  $I_{RM}$  through 25% of  $I_{RM}$  (See Figure 9).
- $Q_{RR}$  = Reverse recovery charge.
- $C_J$  = Junction capacitance.
- $R_{\theta JC}$  = Thermal resistance junction to case.
- $pw$  = Pulse width.
- $D$  = Duty cycle.

**Typical Performance Curves**

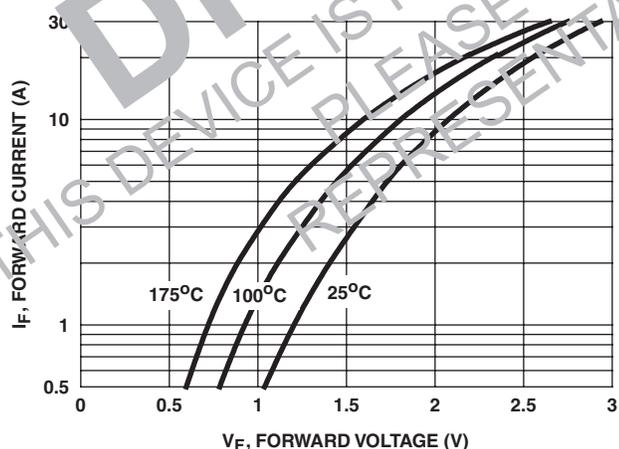


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

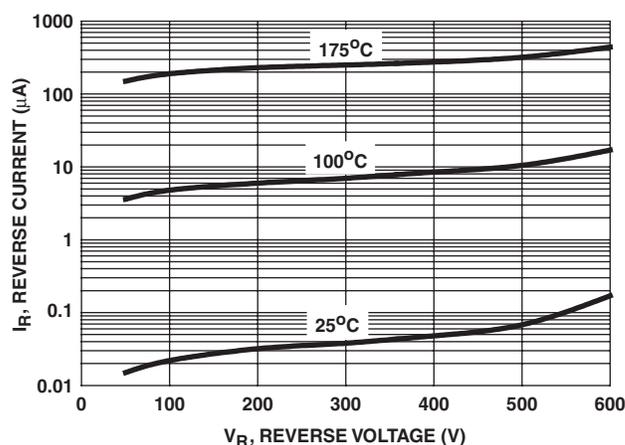


FIGURE 2. REVERSE CURRENT vs REVERSE

Typical Performance Curves (Continued)

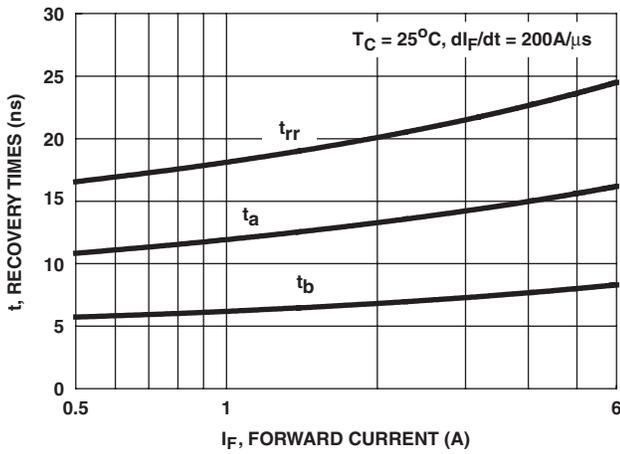


FIGURE 3.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

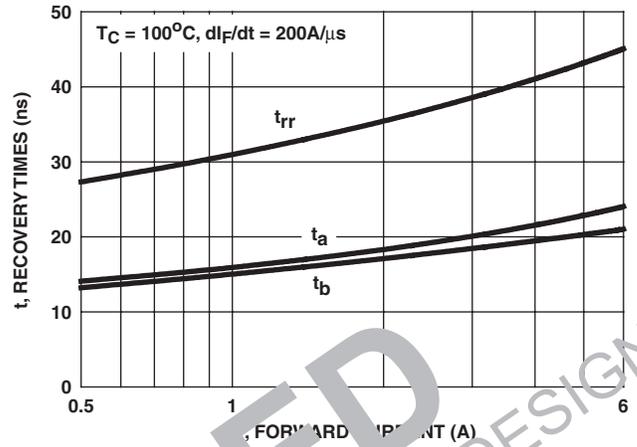


FIGURE 4.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

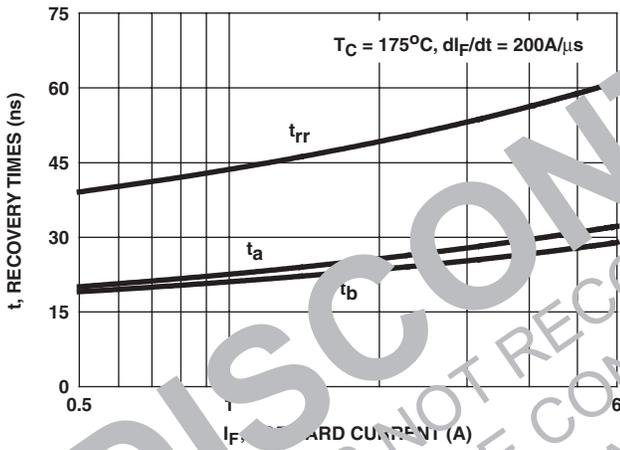


FIGURE 5.  $t_{rr}$  AND  $t_b$  CURVES vs FORWARD CURRENT

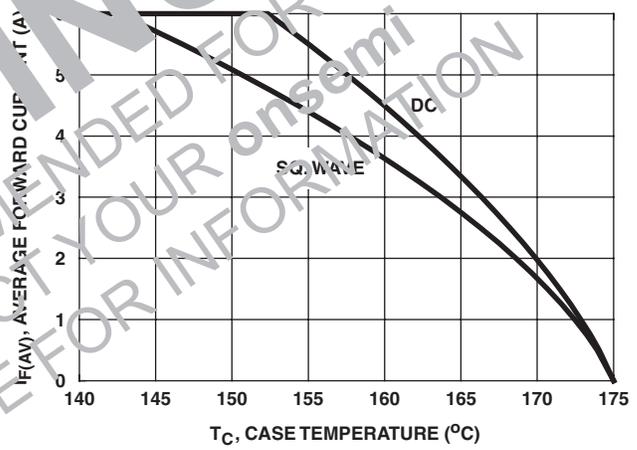


FIGURE 6. CURRENT DERATING CURVE

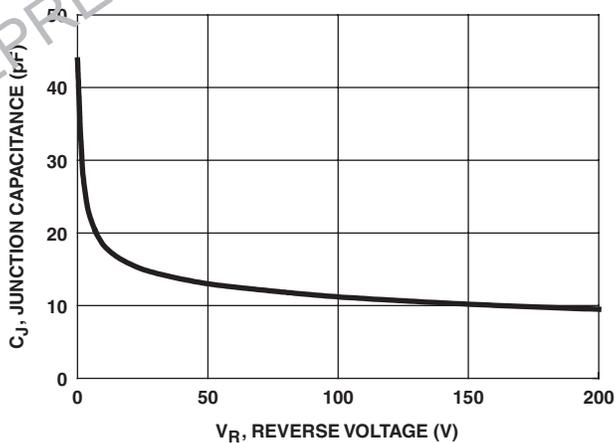


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

**Test Circuits and Waveforms**

$V_{GE}$  AMPLITUDE AND  
 $R_G$  CONTROL  $di_F/dt$   
 $t_1$  AND  $t_2$  CONTROL  $I_F$

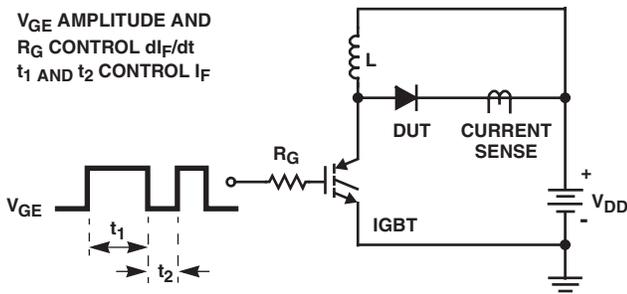


FIGURE 8.  $t_{rr}$  TEST CIRCUIT

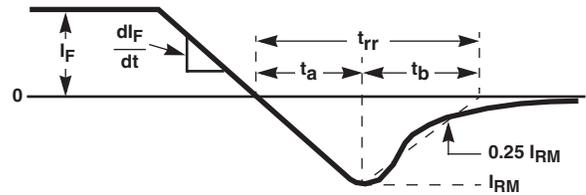


FIGURE 9.  $t_{rr}$  WAVEFORMS AND DEFINITIONS

$I_{MAX} = 1A$   
 $L = 20mH$   
 $R < 0.1\Omega$   
 $E_{AVL} = 1/2LI^2 [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]$   
 $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$

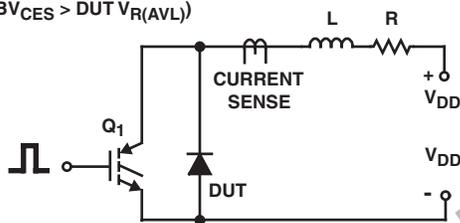


FIGURE 10. AVALANCHE ENERGY TEST CIR

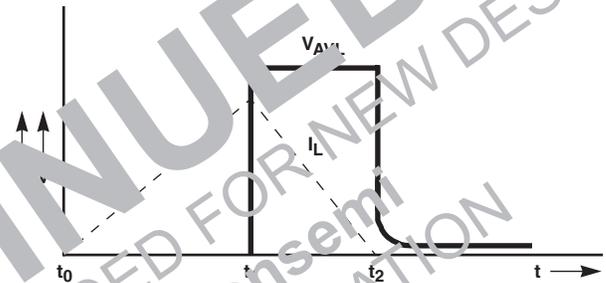


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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